

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC08FN

## Quad 2-Input AND Gate

The TC74VHC08 is an advanced high speed CMOS 2-INPUT AND GATE fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

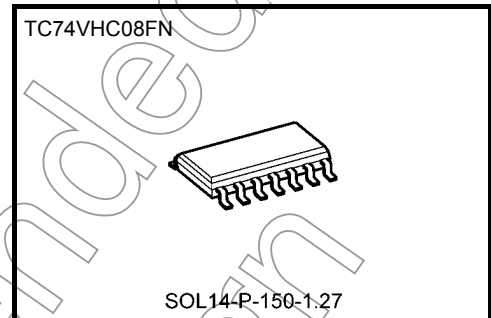
The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

### Features

- High speed:  $t_{pd} = 4.3 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 2 \mu\text{A (max)}$  at  $T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min)}$
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC (opr)} = 2 \text{ V to } 5.5 \text{ V}$
- Low noise:  $V_{OLP} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS08

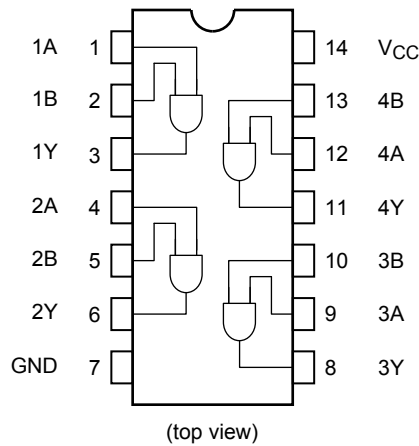
Note: xxxFN (JEDEC SOP) is not available in Japan.



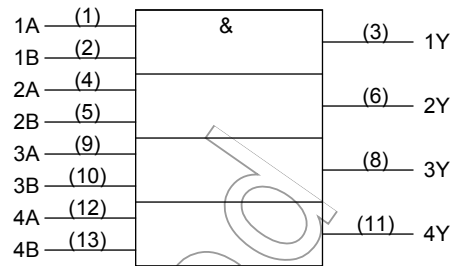
Weight  
SOL14-P-150-1.27 : 0.12 g (typ.)

Not Recommended for New Designs

**Pin Assignment**



**IEC Logic Symbol**



**Truth Table**

| A | B | Y |
|---|---|---|
| L | L | L |
| L | H | L |
| H | L | L |
| H | H | H |

**Absolute Maximum Ratings (Note)**

| Characteristics                    | Symbol           | Rating                        | Unit |
|------------------------------------|------------------|-------------------------------|------|
| Supply voltage range               | V <sub>CC</sub>  | -0.5 to 7.0                   | V    |
| DC input voltage                   | V <sub>IN</sub>  | -0.5 to 7.0                   | V    |
| DC output voltage                  | V <sub>OUT</sub> | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current                | I <sub>IK</sub>  | -20                           | mA   |
| Output diode current               | I <sub>OK</sub>  | ±20                           | mA   |
| DC output current                  | I <sub>OUT</sub> | ±25                           | mA   |
| DC V <sub>CC</sub> /ground current | I <sub>CC</sub>  | ±50                           | mA   |
| Power dissipation                  | P <sub>D</sub>   | 180                           | mW   |
| Storage temperature                | T <sub>stg</sub> | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Operating Ranges (Note)

| Characteristics          | Symbol    | Rating                               | Unit |
|--------------------------|-----------|--------------------------------------|------|
| Supply voltage           | $V_{CC}$  | 2.0 to 5.5                           | V    |
| Input voltage            | $V_{IN}$  | 0 to 5.5                             | V    |
| Output voltage           | $V_{OUT}$ | 0 to $V_{CC}$                        | V    |
| Operating temperature    | $T_{opr}$ | -40 to 85                            | °C   |
| Input rise and fall time | dt/dv     | 0 to 100 ( $V_{CC} = 3.3 \pm 0.3$ V) | ns/V |
|                          |           | 0 to 20 ( $V_{CC} = 5 \pm 0.5$ V)    |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused inputs must be tied to either  $V_{CC}$  or GND.

## Electrical Characteristics

### DC Characteristics

| Characteristics           | Symbol   | Test Condition                  | $T_a = 25^\circ\text{C}$   |                     |      | $T_a = -40$ to $85^\circ\text{C}$ |                     | Unit                |               |   |
|---------------------------|----------|---------------------------------|----------------------------|---------------------|------|-----------------------------------|---------------------|---------------------|---------------|---|
|                           |          |                                 | $V_{CC}$ (V)               | Min                 | Typ. | Max                               | Min                 |                     | Max           |   |
| High-level input voltage  | $V_{IH}$ | —                               | 2.0                        | 1.50                | —    | —                                 | 1.50                | —                   | V             |   |
|                           |          |                                 | 3.0 to 5.5                 | $V_{CC} \times 0.7$ | —    | —                                 | $V_{CC} \times 0.7$ | —                   |               |   |
| Low-level input voltage   | $V_{IL}$ | —                               | 2.0                        | —                   | —    | 0.50                              | —                   | 0.50                | V             |   |
|                           |          |                                 | 3.0 to 5.5                 | —                   | —    | $V_{CC} \times 0.3$               | —                   | $V_{CC} \times 0.3$ |               |   |
| High-level output voltage | $V_{OH}$ | $V_{IN} = V_{IH}$               | $I_{OH} = -50 \mu\text{A}$ | 2.0                 | 1.9  | 2.0                               | —                   | 1.9                 | —             | V |
|                           |          |                                 |                            | 3.0                 | 2.9  | 3.0                               | —                   | 2.9                 | —             |   |
|                           |          |                                 |                            | 4.5                 | 4.4  | 4.5                               | —                   | 4.4                 | —             |   |
|                           |          |                                 | $I_{OH} = -4 \text{ mA}$   | 3.0                 | 2.58 | —                                 | —                   | 2.48                | —             |   |
|                           |          | $I_{OH} = -8 \text{ mA}$        | 4.5                        | 3.94                | —    | —                                 | 3.80                | —                   |               |   |
| Low-level output voltage  | $V_{OL}$ | $V_{IN} = V_{IH}$ or $V_{IL}$   | $I_{OL} = 50 \mu\text{A}$  | 2.0                 | —    | 0.0                               | 0.1                 | —                   | 0.1           | V |
|                           |          |                                 |                            | 3.0                 | —    | 0.0                               | 0.1                 | —                   | 0.1           |   |
|                           |          |                                 |                            | 4.5                 | —    | 0.0                               | 0.1                 | —                   | 0.1           |   |
|                           |          |                                 | $I_{OL} = 4 \text{ mA}$    | 3.0                 | —    | —                                 | 0.36                | —                   | 0.44          |   |
|                           |          |                                 |                            | 4.5                 | —    | —                                 | 0.36                | —                   | 0.44          |   |
| Input leakage current     | $I_{IN}$ | $V_{IN} = 5.5 \text{ V}$ or GND | 0 to 5.5                   | —                   | —    | $\pm 0.1$                         | —                   | $\pm 1.0$           | $\mu\text{A}$ |   |
| Quiescent supply current  | $I_{CC}$ | $V_{IN} = V_{CC}$ or GND        | 5.5                        | —                   | —    | 2.0                               | —                   | 20.0                | $\mu\text{A}$ |   |

**AC Characteristics (input:  $t_r = t_f = 3\text{ ns}$ )**

| Characteristics               | Symbol           | Test Condition      |                     | Ta = 25°C |      |     | Ta = -40 to 85°C |     | Unit |    |
|-------------------------------|------------------|---------------------|---------------------|-----------|------|-----|------------------|-----|------|----|
|                               |                  | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min       | Typ. | Max | Min              | Max |      |    |
| Propagation delay time        | t <sub>pLH</sub> | —                   | 3.3 ± 0.3           | 15        | —    | 6.2 | 8.8              | 1.0 | 10.5 | ns |
|                               |                  |                     |                     | 50        | —    | 8.7 | 12.3             | 1.0 | 14.0 |    |
|                               | t <sub>pHL</sub> |                     | 5.0 ± 0.5           | 15        | —    | 4.3 | 5.9              | 1.0 | 7.0  |    |
|                               |                  |                     |                     | 50        | —    | 5.8 | 7.9              | 1.0 | 9.0  |    |
| Input capacitance             | C <sub>IN</sub>  | —                   |                     | —         | 4    | 10  | —                | 10  | pF   |    |
| Power dissipation capacitance | C <sub>PD</sub>  | (Note)              |                     | —         | 18   | —   | —                | —   | pF   |    |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

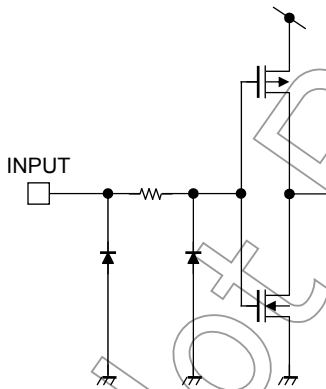
Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

**Noise Characteristics (input:  $t_r = t_f = 3\text{ ns}$ )**

| Characteristics                              | Symbol           | Test Condition      |                     | Ta = 25°C |       | Unit |
|--|------------------|---------------------|---------------------|-----------|-------|------|
|  |                  | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Typ.      | Limit |      |
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | 5.0                 | 50                  | 0.3       | 0.8   | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | 5.0                 | 50                  | -0.3      | -0.8  | V    |
| Minimum high level dynamic input voltage     | V <sub>IHD</sub> | 5.0                 | 50                  | —         | 3.5   | V    |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | 5.0                 | 50                  | —         | 1.5   | V    |

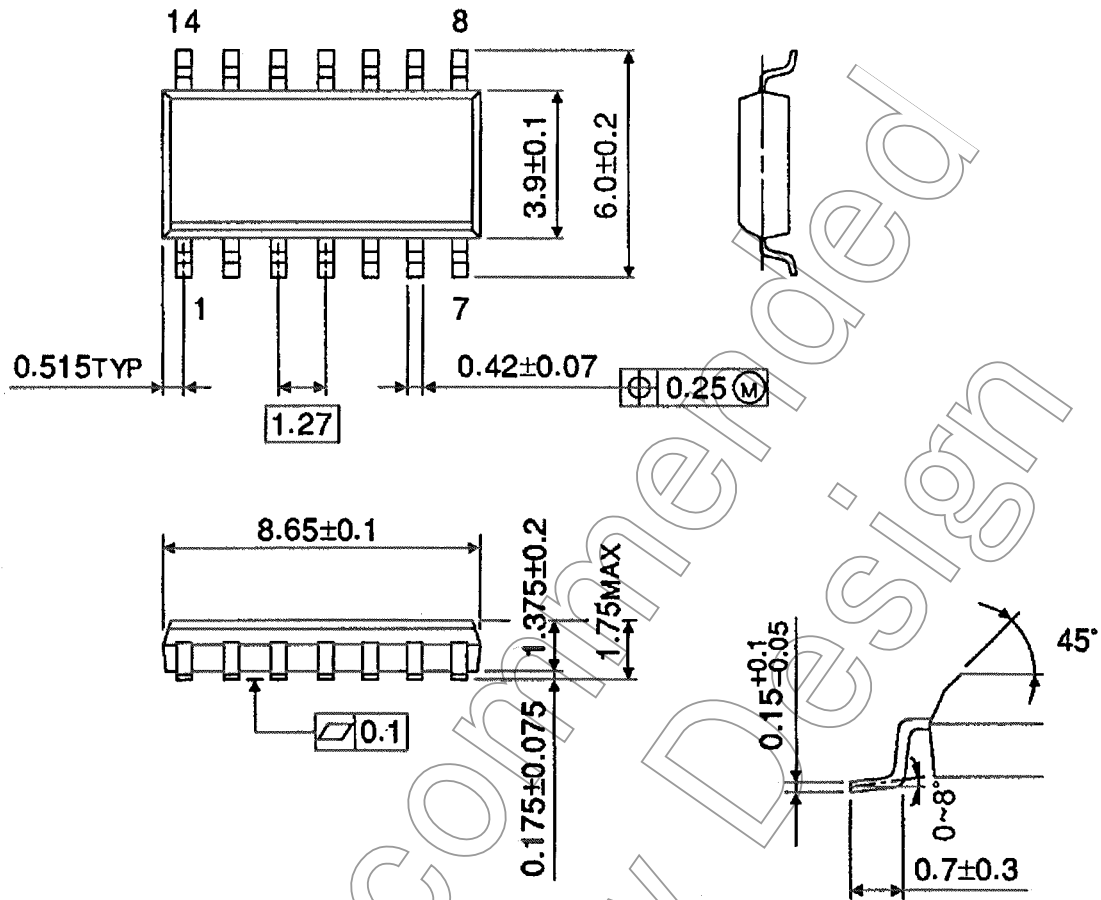
**Input Equivalent Circuit**



Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Not Recommended for New Design

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